

100 V, 2 A PNP high power bipolar transistor 13 July 2017

Product data sheet

1. General description

PNP high power bipolar transistor in a SOT669 (LFPAK56) Surface-Mounted Device (SMD) power plastic package.

NPN complement: PHPT61002NYCLH.

2. Features and benefits

- High thermal power dissipation capability
- Suitable for high temperature applications up to 175 °C •
- Reduced Printed-Circuit Board (PCB) requirements comparing to transistors in DPAK
- High energy efficiency due to less heat generation

3. Applications

- Power management
- Load switch
- Linear mode voltage regulator
- **Backlighting applications**

4. Quick reference data

Table 1. Quick	reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-100	V
I _C	collector current			-	-	-2	А
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$		-	-	-5	А
R _{CEsat}	collector-emitter saturation resistance	I _C = -2 A; I _B = -200 mA; T _{amb} = 25 °C	[1]	-	150	250	mΩ

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$

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5. Pinning information

Table 2. F	inning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter	mb	C .
2	Е	emitter		вщ
3	Е	emitter	a	- M
4	В	base		E sym132
mb	С	collector	1 2 3 4 LFPAK56; Power- SO8 (SOT669)	

6. Ordering information

Table 3. Ordering infor	mation					
Type number	Package					
	Name	Description	Version			
PHPT61002PYCLH	LFPAK56; Power-SO8	Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads	SOT669			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PHPT61002PYCLH	1002PCC

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

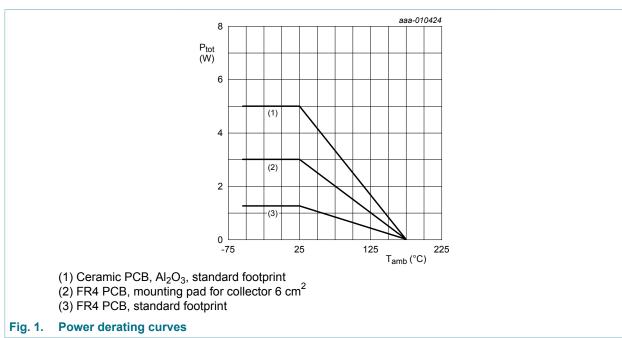
Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CBO}	collector-base voltage	open emitter		-	-100	V
V _{CEO}	collector-emitter voltage	open base		-	-100	V
V _{EBO}	emitter-base voltage	open collector		-	-8	V
I _C	collector current			-	-2	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-5	А
I _B	base current			-	-0.5	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	1.25	W
			[2]	-	3	W
			[3]	-	5	W
			[4]	-	25	W
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 6 cm².

[3] Device mounted on a ceramic PCB, Al_2O_3 , standard footprint.

[4] Power dissipation from junction to mounting base.



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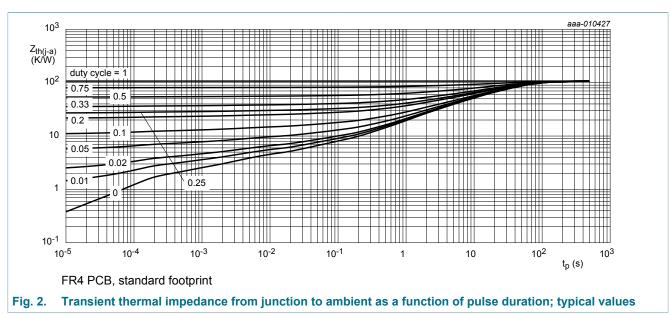
9. Thermal characteristics

Table 6. The	ermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	115	K/W
			[2]	-	-	50	K/W
			[3]	-	-	30	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	6	K/W

Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint. [1]

Device mounted on an FR4 PCB, single-sided copper, tin-plated mounting pad for collector 6 cm². [2] [3]

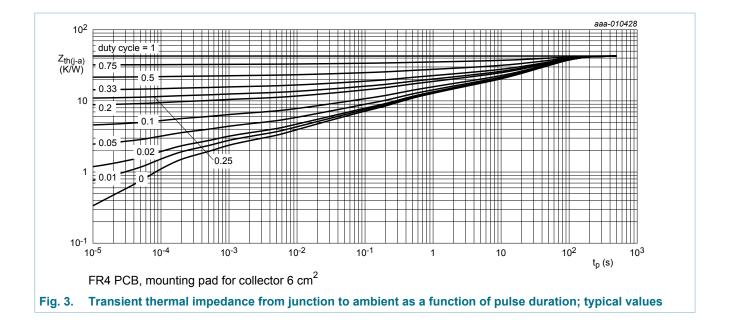
Device mounted on a ceramic PCB, Al₂O₃, standard footprint.



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10. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = -80 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
	current	V _{CB} = -80 V; I _E = 0 A; T _j = 150 °C		-	-	-50	μA
I _{CES}	collector-emitter cut-off current	V_{CE} = -80 V; V_{BE} = 0 V; T_{amb} = 25 °C		-	-	-100	nA
I _{EBO}	emitter-base cut-off current	V_{EB} = -8 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = -1.5 V; I _C = -500 mA; T _{amb} = 25 °C	[1]	80	160	-	
		V _{CE} = -10 V; I _C = -500 mA; T _{amb} = 25 °C	[1]	100	180	-	
		V_{CE} = -5 V; I _C = -1 A; T _{amb} = 25 °C	[1]	70	150	260	
		V_{CE} = -10 V; I _C = -1 A; T _{amb} = 25 °C	[1]	90	160	-	
		V_{CE} = -10 V; I _C = -2 A; T _{amb} = 25 °C	[1]	20	70	-	
OLOUI	collector-emitter	I_{C} = -0.5 A; I_{B} = -50 mA; T_{amb} = 25 °C		-	-75	-130	mV
	saturation voltage	I_{C} = -2 A; I_{B} = -200 mA; T_{amb} = 25 °C	[1]	-	-300	-500	mV
R _{CEsat}	collector-emitter saturation resistance			-	150	250	mΩ
V _{BEsat}	base-emitter saturation voltage			-	-1.02	-1.2	V
V _{BEon}	base-emitter turn-on voltage	V_{CE} = -2 V; I_{C} = -0.1 A; T_{amb} = 25 °C	[1]	-	-0.67	-0.9	V
t _d	delay time	V _{CC} = -12.5 V; I _C = -1 A; I _{Bon} = -50 mA;		-	20	-	ns
t _r	rise time	I _{Boff} = 50 mA; T _{amb} = 25 °C		-	190	-	ns
t _{on}	turn-on time			-	210	-	ns
t _s	storage time			-	300	-	ns
t _f	fall time			-	170	-	ns
t _{off}	turn-off time			-	470	-	ns
f _T	transition frequency	V _{CE} = -10 V; I _C = -100 mA; f = 100 MHz; T _{amb} = 25 °C		-	125	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	28	-	pF

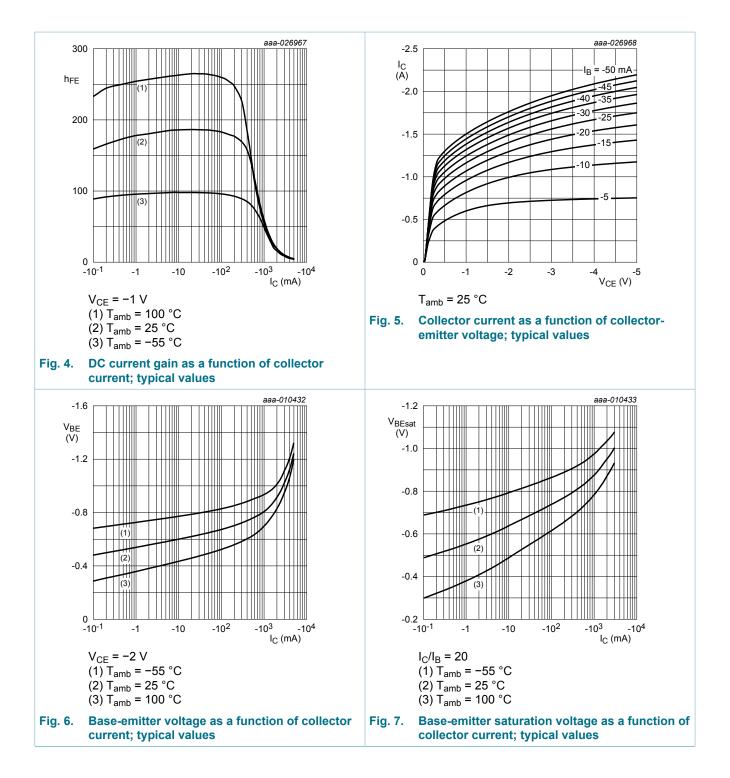
[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02$

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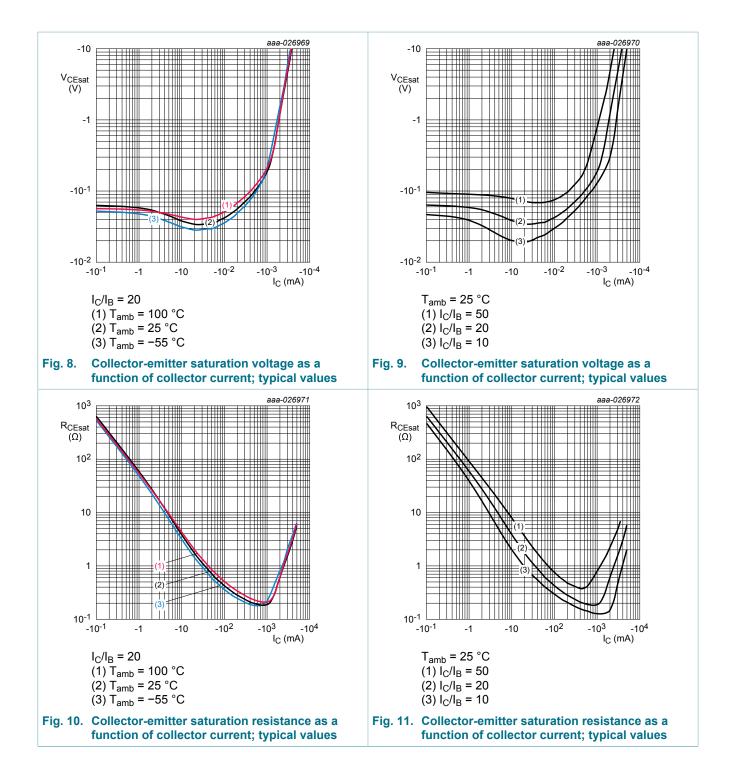


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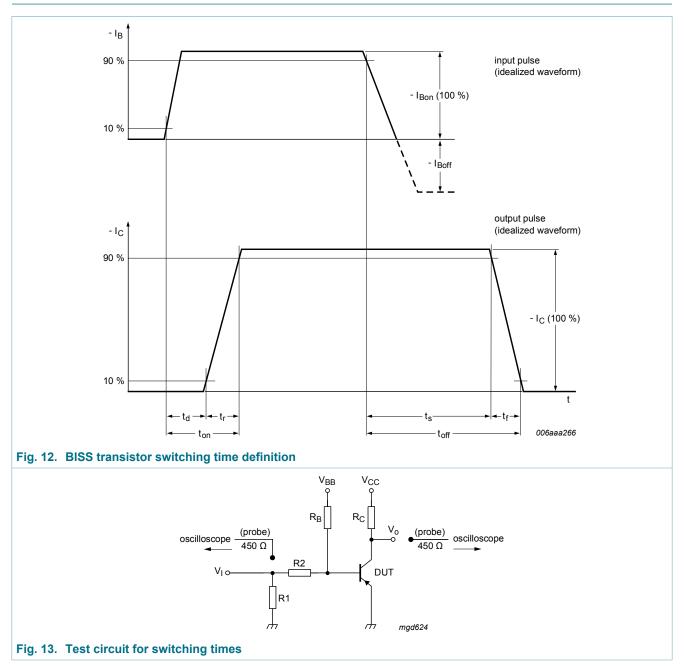
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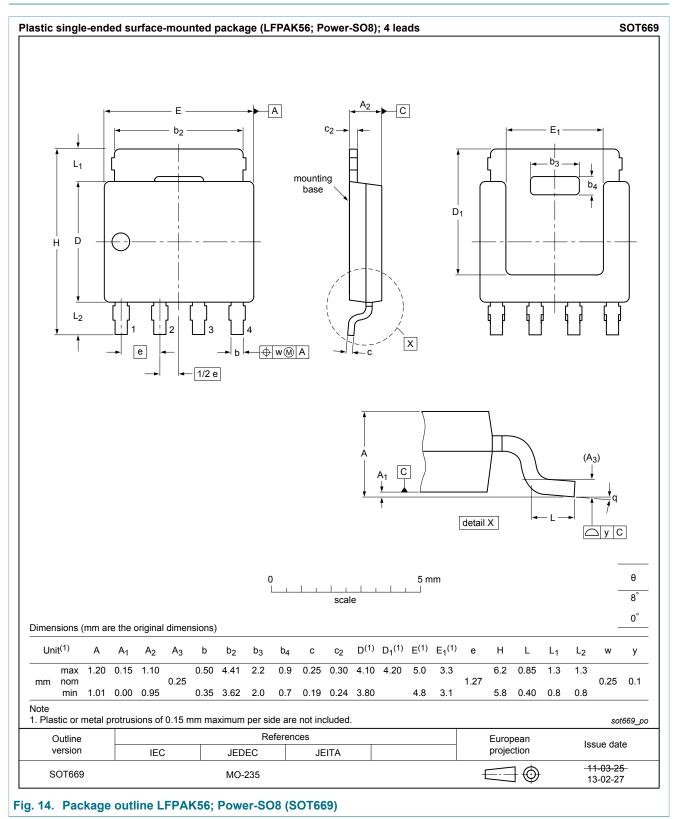
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11. Test information

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12. Package outline



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13. Soldering

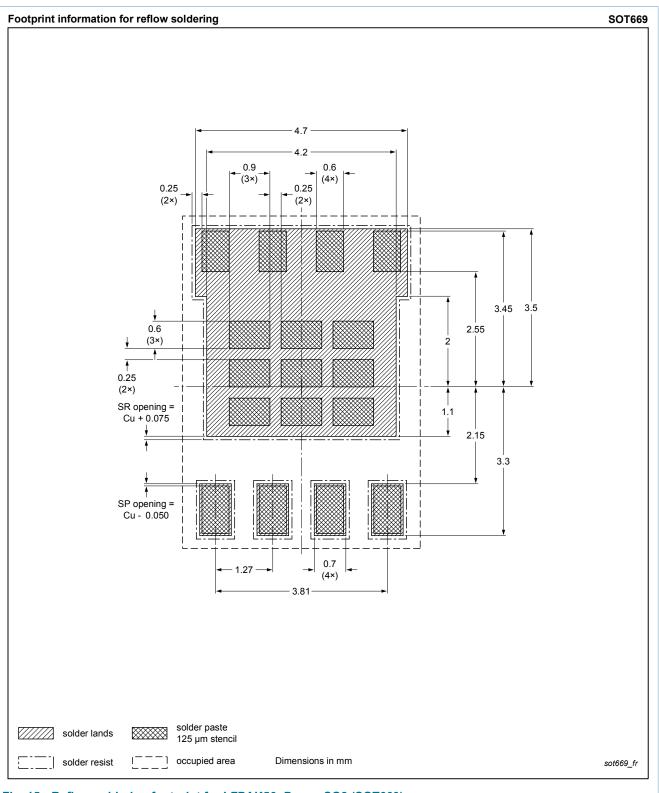


Fig. 15. Reflow soldering footprint for LFPAK56; Power-SO8 (SOT669)

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14. Revision history

Table 8. Revision history				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PHPT61002PYCLH v.1	20170713	Product data sheet	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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